# FAIRCHILD

SEMICONDUCTOR®

# FDD8444L\_F085

# N-Channel PowerTrench<sup>®</sup> MOSFET

# 40V, 50A, 6.0m $\Omega$

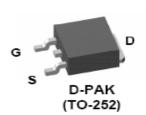
## Features

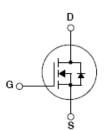
- Typ  $r_{DS(on)}$  = 3.8m $\Omega$  at  $V_{GS}$  = 5V,  $I_D$  = 50A
- Typ Q<sub>g(tot)</sub> = 46nC at V<sub>GS</sub> = 5V
- Low Miller Charge
- Low Q<sub>rr</sub> Body Diode
- UIS Capability (Single Pulse/ Repetitive Pulse)
- Qualified to AEC Q101
- RoHS Compliant



# Applications

- Automotive Engine Control
- Powertrain Management
- Solenoid and Motor Drivers
- Electronic Transmission
- Distributed Power Architecture and VRMs
- Primary Switch for 12V and 24V systems





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January 2009

MOSF	<b>ET Maximum Ratings</b> $T_{C} = 25^{\circ}C$ unless otherwise	noted		
Symbol	Parameter		Ratings	Units
V <sub>DSS</sub>	Drain to Source Voltage		40	V
V <sub>GS</sub>	Gate to Source Voltage		±20	V
	Drain Current Continuous (T <sub>C</sub> < 150°C, V <sub>GS</sub> = 10V)	(Note 1)	50	
I <sub>D</sub>	Continuous ( $T_{amb}$ = 25°C, $V_{GS}$ = 10V, with $R_{\theta JA}$ = 52°C/W)		16	А
	Pulsed		See Figure 4	
E <sub>AS</sub>	Single Pulse Avalanche Energy	(Note 2)	295	mJ
	Power Dissipation		153	W
PD	Derate above 25°C		1.02	W/ºC
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature		-55 to +175	°C

## **Thermal Characteristics**

$R_{\thetaJC}$	Thermal Resistance, Junction to Case	0.98	°C/W
$R_{\thetaJA}$	Thermal Resistance, Junction to Ambient TO-252, 1in <sup>2</sup> copper pad area	52	°C/W

# Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDD8444L	FDD8444L_F085	TO-252AA	13"	12mm	2500 units

# **Electrical Characteristics** $T_J$ = 25°C unless otherwise noted

Symbol Parameter lest Conditions Min Typ Max Units	O	Demonster	To all Q and shift and a		<b>T</b>		11
	Symbol		Test Conditions	Min	Тур	Max	Units

## **Off Characteristics**

B <sub>VDSS</sub>	Drain to Source Breakdown Voltage	I <sub>D</sub> = 250μA, V <sub>GS</sub>	$I_{D} = 250 \mu A, V_{GS} = 0V$		-	-	V
	Zara Cata Valtaga Drain Current	V <sub>DS</sub> = 32V,		-	-	1	A
DSS	I <sub>DSS</sub> Zero Gate Voltage Drain Current	$V_{GS} = 0V$	T <sub>J</sub> = 150 <sup>o</sup> C	-	-	250	μA
I <sub>GSS</sub>	Gate to Source Leakage Current	V <sub>GS</sub> = ±20V		-	-	±100	nA

## **On Characteristics**

V <sub>GS(th)</sub>	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = 250 \mu A$	1	1.8	3	V
		I <sub>D</sub> = 50A, V <sub>GS</sub> = 10V	-	3.5	5.2	
		I <sub>D</sub> = 50A, V <sub>GS</sub> = 5V	-	3.8	6.0	
r <sub>DS(on)</sub>	Drain to Source On Resistance	I <sub>D</sub> = 50A, V <sub>GS</sub> = 4.5V	-	4.0	6.5	mΩ
		I <sub>D</sub> = 50A, V <sub>GS</sub> = 5V, T <sub>J</sub> = 175 <sup>o</sup> C	-	6.8	10.7	

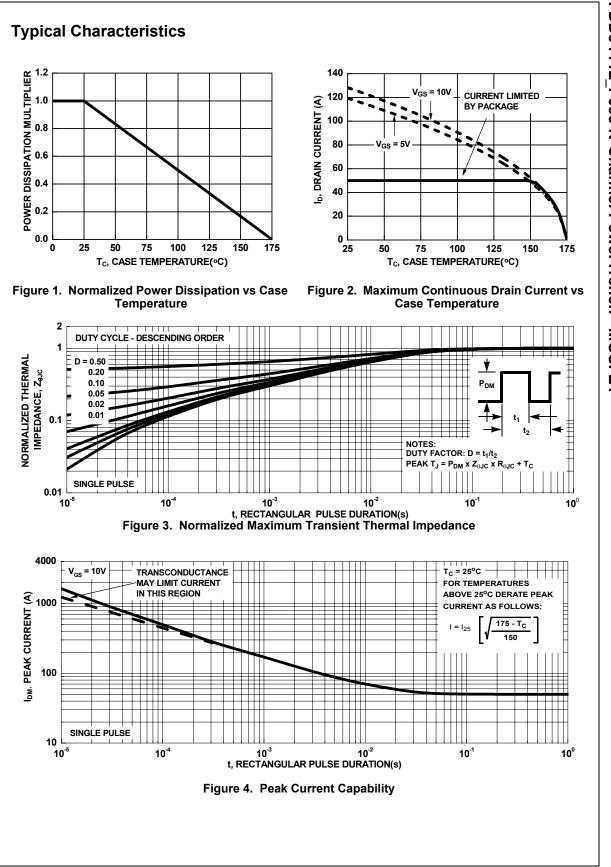
## **Dynamic Characteristics**

C <sub>iss</sub>	Input Capacitance		$V_{DS} = 25V, V_{GS} = 0V,$		5530	-	pF
C <sub>oss</sub>	Output Capacitance	V <sub>DS</sub> = 25V, V <sub>GS</sub> = f = 1MHz			605	-	pF
C <sub>rss</sub>	Reverse Transfer Capacitance			-	400	-	pF
R <sub>G</sub>	Gate Resistance	f = 1MHz		-	1.7	-	Ω
Q <sub>g(TOT)</sub>	Total Gate Charge at 5V	$V_{GS}$ = 0 to 5V		-	46	60	nC
Q <sub>g(TH)</sub>	Threshold Gate Charge	$V_{GS}$ = 0 to 2V	V <sub>DD</sub> = 20V	-	5.4	7	nC
Q <sub>gs</sub>	Gate to Source Gate Charge		I <sub>D</sub> = 50A	-	16.3	-	nC
Q <sub>gs2</sub>	Gate Charge Threshold to Plateau		I <sub>g</sub> = 1.0mA	-	10.9	-	nC
Q <sub>gd</sub>	Gate to Drain "Miller" Charge			-	21	-	nC

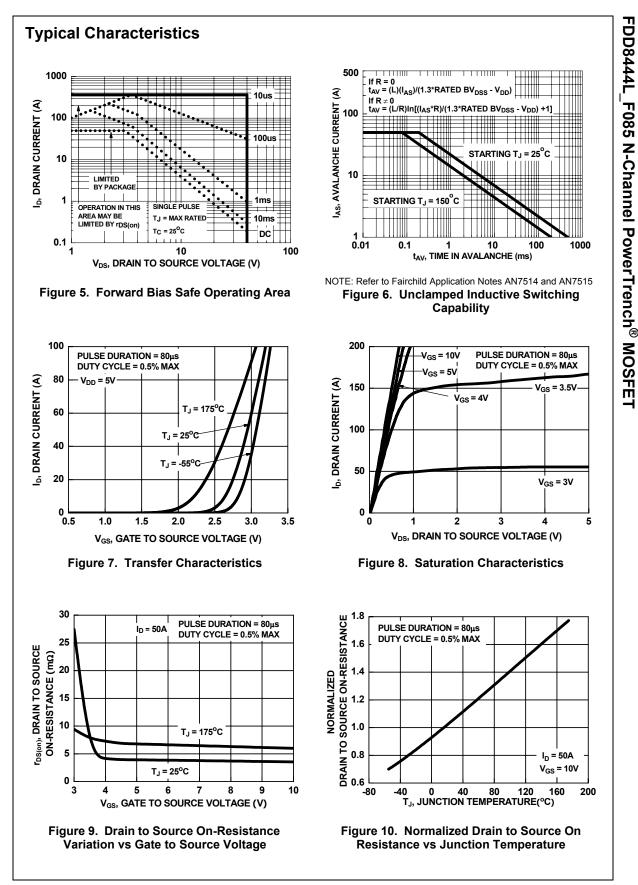
	Parameter	Test Conditions	Min	Тур	Max	Units
Switch	ing Characteristics					
on	Turn-On Time		-	-	104	ns
d(on)	Turn-On Delay Time		-	18.7	-	ns
t <sub>r</sub>	Turn-On Rise Time	$V_{DD} = 20V, I_D = 50A$	-	46	-	ns
d(off)	Turn-Off Delay Time	—V <sub>GS</sub> = 5V, R <sub>GS</sub> = 2Ω	-	42	-	ns
lf	Turn-Off Fall Time		-	19.2	-	ns
off	Turn-Off Time		-	-	96	ns
	ource Diode Characteristics	I <sub>SD</sub> = 50A	-	0.9	1.25	
V <sub>SD</sub>	Source to Drain Diode Voltage	I <sub>SD</sub> = 25A	-	0.8	1.0	V
rr	Reverse Recovery Time	I <sub>F</sub> = 50A, dI <sub>F</sub> /dt = 100A/μs	-	34	44	ns
Q <sub>rr</sub>	Reverse Recovery Charge	—— I <sub>F</sub> = 50A, dI <sub>F</sub> /dt = 100A/μs	-	29	38	nC

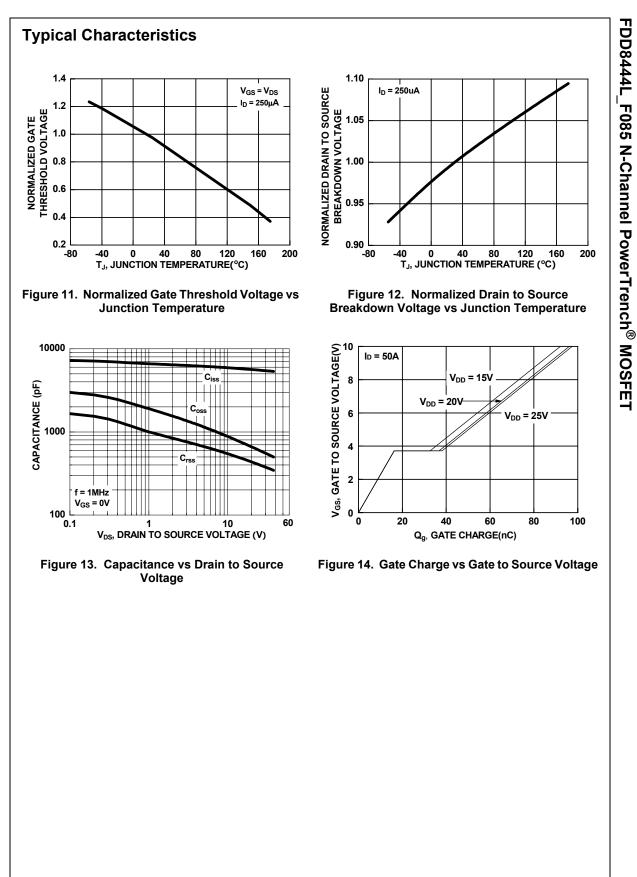
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